PWP PowerPAD™ PACKAGE

SLVS289 - MARCH 2000

#### 2.8 V – 5.5 V Input Voltage Range

- Programmable Dual Output Controller Supports Popular DSP, FPGA and Microcontroller Core and I/O Voltages
  - Switching Regulator Controls I/O Voltage
  - Low Dropout Controller Regulates Core Voltage
- Adjustable Slow-Start for Simultaneous Powerup of Both Outputs
- Power Good Output Monitors Both Outputs
- Fast Ripple Regulator Reduces Bulk Capacitance for Lower System Costs
- ±1.5% Reference Voltage Tolerance
- Efficiencies Greater Than 90%
- Overvoltage, Undervoltage, and Adjustable Overcurrent Protection
- Drives Logic Level N-Channel MOSFETs Through Entire Input Voltage Range
- Evaluation Module TPS56302EVM-163 Available

#### (TOP VIEW) VID0 I 28 ☐ DROOP 2 27 VID1 I □ OCP 26 TOUT SLOWST FT 25 VHYST I ☐ PWRGD VREFB □□ 5 24 □ VSEN-LDO VSEN-RR □ 6 23 □ NGATE-LDO **Thermal** 7 22 ANAGND I Pad BIAS 🞞 8 21 ☐ IOUTLO VLDODRV I 9 20 ☐ HISENSE 19 CPC1 □□ 10 ☐ LOSENSE/LOHIB 18 ☐ HIGHDR V<sub>CC</sub> □ 11 CPC2 □□ □ BOOT 12 17 VDRV I 13 16 □ BOOTLO DRVGND □ 14 15 □ LDWDR

#### **AVAILABLE VID CODE RANGES**

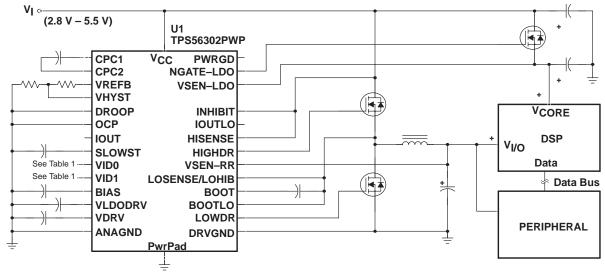
| OUTPUTS                    | TPS56302       | TPS56300       |
|----------------------------|----------------|----------------|
| V <sub>OUT</sub> -LDO      | 1.3 V TO 2.5 V | 1.3 V TO 3.3 V |
| V <sub>OUT</sub> -Switcher | 1.3 V TO 3.3 V | 1.3 V TO 2.5 V |

NOTE: See Table 1 for actual VID codes.

#### description

The high-performance TPS56302 synchronous-buck regulator provides two supply voltages to power the core and I/O of digital signal processors. The TPS56302 is identical to the TPS56300 except that the reference voltages of the LDO and switching regulator have been reversed. The switching regulator, using hysteretic control with droop compensation, supports high current and efficiency for the I/O and other peripheral components. The LDO controller, suitable for powering the core voltage, drives an external N-channel power MOSFET and functions as an LDO regulator and as a power distribution switch.

#### typical design





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TEXAS INSTRUMENTS

#### description (continued)

To promote better system reliability during power up, voltage sequencing and protection are controlled such that the core and I/O power up together with the same slow-start voltage. At power down, the LDO and ripple regulator are discharged towards ground for added protection. The TPS56302 also includes inhibit, slow-start, and under-voltage lockout features to aide in controlling power sequencing. A tri-level voltage identification definition (VID) sets both regulated voltages to any of 9 preset voltage pairs from 1.3 V to 3.3 V. Other voltages are possible by implementing an external voltage divider. Strong MOSFET drivers, with a typical peak current rating of 2-A sink and source are included on chip, which allows paralleling MOSFETs to be driven and allowing higher current to be controlled. The high-side driver features a floating bootstrap driver with an internal bootstrap synchronous rectifier. Many protection features are incorporated within the device to ensure better system integrity. An open-drain output power good status circuit monitors both output voltages, and is pulled low if either output falls below the threshold. An over current shutdown circuit protects the high-side power MOSFET against short-to-ground faults, while over voltage protection turns off the output drivers and LDO controller if either output exceeds its threshold. Under voltage protection turns off the high-side and low-side MOSFET drivers and the LDO controller if either output is 25% below V<sub>REF</sub>. Lossless current-sensing is implemented by detecting the drain-source voltage drop across the high-side power MOSFET while it is conducting. The TPS56302 is fully compliant with TI DSP power requirements.

#### **AVAILABLE OPTIONS**

|                | PACKAGES        |                           |
|----------------|-----------------|---------------------------|
| TJ             | TSSOP†<br>(PWP) | EVALUATION MODULE         |
| –40°C to 125°C | TPS56302PWP     | TPS56302EVM-163 (SLVP163) |

<sup>†</sup> The PWP package is also available taped and reel. To order, add an R to the end of the part number (e.g., TPS56302PWPR).

Table 1. Voltage Identification Code¶#

|         | Table 1. Voltage Identification Code |                                 |                                |                                |                                 |  |  |  |  |
|---------|--------------------------------------|---------------------------------|--------------------------------|--------------------------------|---------------------------------|--|--|--|--|
| VID TER | MINALS‡                              | 563                             | 302                            | 56300                          |                                 |  |  |  |  |
| VID1    | VID0                                 | V <sub>REF-LDO</sub> #<br>(VDC) | V <sub>REF-RR</sub> #<br>(VDC) | V <sub>REF-RR</sub> #<br>(VDC) | V <sub>REF-LDO</sub> #<br>(VDC) |  |  |  |  |
| 0       | 0                                    | 1.30                            | 1.50                           | 1.30                           | 1.50                            |  |  |  |  |
| 0       | 1                                    | 1.50                            | 1.80                           | 1.50                           | 1.80                            |  |  |  |  |
| 0       | 2                                    | 1.30                            | 1.80                           | 1.30                           | 1.80                            |  |  |  |  |
| 1       | 0                                    | 1.80                            | 3.30                           | 1.80                           | 3.30                            |  |  |  |  |
| 1       | 1                                    | 1.30                            | 1.30                           | 1.30                           | 1.30                            |  |  |  |  |
| 1       | 2                                    | 2.50                            | 3.30                           | 2.50                           | 3.30                            |  |  |  |  |
| 2       | 0                                    | 1.30                            | 2.50                           | 1.30                           | 2.50                            |  |  |  |  |
| 2       | 1                                    | 1.50                            | 3.30                           | 1.50                           | 3.30                            |  |  |  |  |
| 2       | 2                                    | 1.80                            | 2.50                           | 1.80                           | 2.50                            |  |  |  |  |

 $<sup>\</sup>ddagger$ 0 = ground (GND), 1 = floating(V<sub>BIAS</sub>/2), 2 = (V<sub>BIAS</sub>)

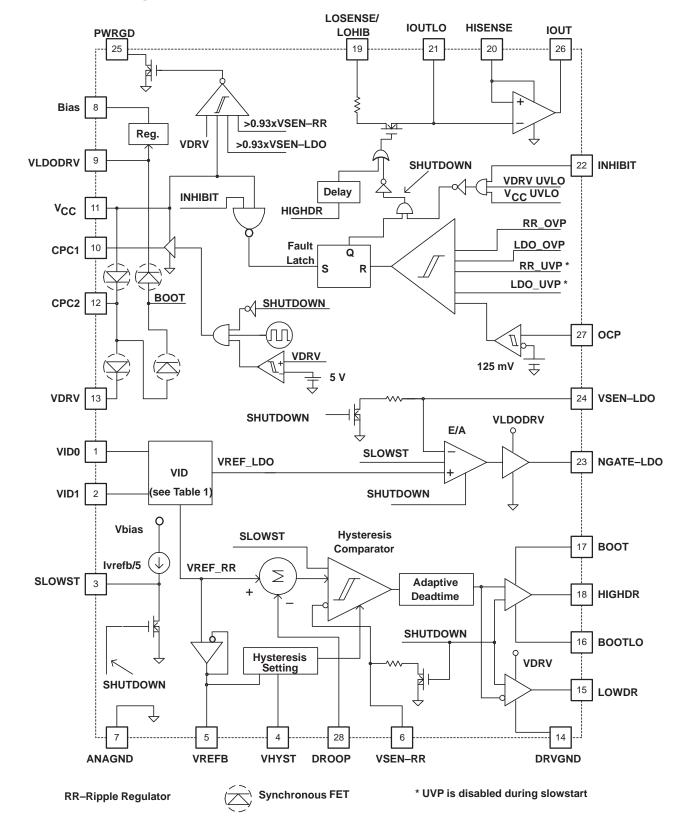


<sup>§</sup> RR = Ripple Regulator, LDO = Low Drop-Out Regulator

<sup>¶</sup> V<sub>BIAS</sub>/2 is internal, leave the VID pin floating. Adding an external 0.1-μF capacitor to ANAGND may be used

<sup>#</sup> External resistors may be used as a voltage divider (from VOLIT to VSEN-xx to ground) to program output voltages to other values.

#### functional block diagram





#### **Terminal Functions**

| TERMINAL          |     |                                                                                                                                                                                                                                                                                                             |
|-------------------|-----|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME              | NO. | DESCRIPTION                                                                                                                                                                                                                                                                                                 |
| VID0              | 1   | Voltage Identification input 0. The VID pins are tri-level programming pins that set the output voltages for both converters. The code pattern for setting the output voltage is located in table 1. The VID pins are internally pulled to VBIAS/2, allowing floating voltage set to logic 1 (see Table 1). |
| VID1              | 2   | Voltage Identification input 1 (see VID0 pin description and Table 1).                                                                                                                                                                                                                                      |
| SLOWST            | 3   | Slow-start (soft start). A capacitor from pin 3 to GND sets the slow-start time for V <sub>OUT-RR</sub> and V <sub>OUT-LDO</sub> . Both supplies will ramp-up together while tracking the slow-start voltage.                                                                                               |
| VHYST             | 4   | Hysteresis set pin. The hysteresis equals 2 × (VREFB – VHYST).                                                                                                                                                                                                                                              |
| VREFB             | 5   | Buffered ripple regulator reference voltage from VID network.                                                                                                                                                                                                                                               |
| VSEN-RR           | 6   | Ripple regulator voltage sense input. This pin is connected to the ripple regulator output. It is used to sense the ripple regulator voltage for regulation, OVP, UVP, and power good functions It is recommended that an RC low pass filter be connected at this pin to filter high frequency noise.       |
| ANAGND            | 7   | Analog ground                                                                                                                                                                                                                                                                                               |
| BIAS              | 8   | Analog BIAS pin. Recommended that a 1-μF capacitor be connected to ANAGND.                                                                                                                                                                                                                                  |
| VLDODRV           | 9   | Output of charge pump generated through bootstrap diode. Approximately equal to VDRV + $V_{\text{IN}}$ – 300 mV. Used as supply for LDO driver and bias regulator. Recommended that a 1- $\mu$ F capacitor be connected to DRVGND.                                                                          |
| CPC1              | 10  | Connect one end of charge pump capacitor. Recommended that a 1-µF capacitor be connected from CPC1 to CPC2.                                                                                                                                                                                                 |
| VCC               | 11  | $3.3~V~or~5~V~supply~(2.8~V-5.5~V)$ . It is recommended that a low ESR capacitor be connected directly from $V_{CC}$ to DRVGND (bulk capacitors supplied at power stage input).                                                                                                                             |
| CPC2              | 12  | Other end of charge pump capacitor from CPC1.                                                                                                                                                                                                                                                               |
| VDRV              | 13  | Regulated output of internal charge pump. Supplies DRIVE charge for the low-side MOSFET driver (5 V). Recommended that a 10-μF capacitor be connected to DRVGND.                                                                                                                                            |
| DRVGND            | 14  | Drive ground. Ground for FET drivers. Connect to source of low-side FET.                                                                                                                                                                                                                                    |
| LOWDR             | 15  | Low drive. Output drive to synchronous rectifier low-side FET.                                                                                                                                                                                                                                              |
| BOOTLO            | 16  | Bootstrap low. This pin connects to the junction of the high-side and low-side FETs.                                                                                                                                                                                                                        |
| воот              | 17  | Bootstrap pin. Connect a 1-µF low ESR capacitor to BOOTLO to generate floating drive for the high-side FET driver.                                                                                                                                                                                          |
| HIGHDR            | 18  | High drive. Output drive to high-side power switching FETs                                                                                                                                                                                                                                                  |
| LOSENSE/<br>LOHIB | 19  | Low sense/low-side inhibit. This pin is connected to the junction of the high and low-side FETs and is used in current sensing and the anti-cross-conduction to eliminate shoot-through current.                                                                                                            |
| HISENSE           | 20  | High current sense. For current sensing across high-side FETs, connect to the drain of the high-side FETs.                                                                                                                                                                                                  |
| IOUTLO            | 21  | Current sense low output. Voltage on this pin is the voltage on the LOSENSE pin when the high-side FETs are on.                                                                                                                                                                                             |
| INHIBIT           | 22  | This pin inhibits the drive signals to the MOSFET drivers. The IC is in a low-current state if INHIBIT is grounded. It is recommended that an external pullup resistor be connected to 5 V.                                                                                                                 |
| NGATE-LDO         | 23  | Drives external N-channel power MOSFET to regulate LDO voltage to VREF-LDO.                                                                                                                                                                                                                                 |
| VSEN-LDO          | 24  | LDO voltage sense. This pin is connected to the LDO output. It is used to sense the LDO voltage for regulation, OVP, UVP, and power good functions.                                                                                                                                                         |
| PWRGD             | 25  | Power good. Power good signal goes high when output voltage is above 93% of V <sub>REF</sub> for both ripple regulator and LDO. This is an open-drain output.                                                                                                                                               |
| IOUT              | 26  | Current signal output. Output voltage on this pin is proportional to the load current as measured across the high-side FETs on-resistance. The voltage on this pin equals $2 \times R_{ON} \times IOUT$ , where $R_{ON}$ is the equivalent on-resistance of the high-side FETs                              |
| OCP               | 27  | Over current protection. Current limit trip point for ripple regulator is set with a resistor divider between the IOUT pin and ANAGND. The trip point is typically 125 mV.                                                                                                                                  |
| DROOP             | 28  | Droop voltage. Voltage input used to set the amount of output voltage droop as a function of load current. The amount of droop compensation is set with a resistor divider between the IOUT pin and ANAGND.                                                                                                 |



#### absolute maximum ratings over operating virtual junction temperature (unless otherwise noted)†

| Supply voltage range   | 0 V (soo Noto1)                                         | 0.3 \/ to 6 \/                               |
|------------------------|---------------------------------------------------------|----------------------------------------------|
| Input voltage range:   | e, V <sub>CC</sub> (see Note1)                          | _0.3 V to 7 V                                |
| iliput voltage lalige. | BOOT to DRVGND (High-side Driver ON)                    |                                              |
|                        |                                                         |                                              |
|                        | BOOT to BOOTLO                                          |                                              |
|                        | BOOT to HIGHDRY                                         |                                              |
|                        | BOOTLO to DRVGND                                        |                                              |
|                        | DRV to DRVGND                                           |                                              |
|                        | BIAS to ANAGND                                          |                                              |
|                        | INHIBIT                                                 |                                              |
|                        | DROOP                                                   |                                              |
|                        | OCP                                                     | –0.3 V to 7 V                                |
|                        | VID0, VID1 (tri-level terminals)                        | $-0.3 \text{ V to V}_{BIAS} + 0.3 \text{ V}$ |
|                        | PWRGD                                                   | 0.3 V to 6 V                                 |
|                        | LOSENSE, LOHIB                                          | –0.5 V to 14 V                               |
|                        | IOUTLO                                                  | 0.3 V to 14 V                                |
|                        | HISENSE                                                 | 0.3 V to 7 V                                 |
|                        | VSEN-LDO                                                | 0.3 V to 6 V                                 |
|                        | VSEN-RR                                                 |                                              |
| Voltage difference be  | etween ANAGND and DRVGND                                |                                              |
| •                      | ver dissipation                                         |                                              |
|                        | emperature range, T <sub>J</sub>                        |                                              |
| Storage temperature    | e range, T <sub>stg</sub>                               | _65°C to 150°C                               |
| Lead temperature so    | oldering 1,6 mm (1/16 inch) from case for 10 seconds.   | 30000                                        |
| Lead temperature st    | defining 1,0 mini (1/10 mon) nomi case for 10 seconds . |                                              |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Unless otherwise specified, all voltages are with respect to ANAGND.

#### **DISSIPATION RATING TABLE**

| PWP                 | T <sub>A</sub> < 25°C | DERATING FACTOR‡ | T <sub>A</sub> = 70°C | T <sub>A</sub> = 85°C |
|---------------------|-----------------------|------------------|-----------------------|-----------------------|
| PowerPAD™ mounted   | 3.58 W                | 0.0358 W/°C      | 1.96 W                | 1.43 W                |
| PowerPAD™ unmounted | 1.78 W                | 0.0178 W/°C      | 0.98 W                | 0.71 W                |

<sup>‡</sup> Test Board Conditions:

- 1.. Thickness: 0.062"
- 2. 3"×3"
- 3. 2 oz. Copper traces located on the top of the board (0.071 mm thick)
- 4. Copper areas located on the top and bottom of the PCB for soldering
- 5. Power and ground planes, 1 oz. Copper (0.036 mm thick)
- 6. Thermal vias, 0.33 mm diameter, 1.5 mm pitch
- 7. Thermal isolation of power plane

For more information, refer to TI technical brief SLMA002.

#### JUNCTION-CASE THERMAL RESISTANCE TABLE

| Junction-case thermal resistance | 0.72 °C/W |
|----------------------------------|-----------|
|----------------------------------|-----------|



# TPS56302 DUAL-OUTPUT LOW-INPUT-VOLTAGE DSP POWER SUPPLY CONTROLLER WITH SEQUENCING

SLVS289 - MARCH 2000

# electrical characteristics $T_J$ = 0° to 125°C, $V_{CC}$ = 2.8 V to 5.5 V (unless otherwise noted)

#### input

|     | PARAMETER            | TEST CONDITIONS                      | MIN | TYP | MAX | UNITS |
|-----|----------------------|--------------------------------------|-----|-----|-----|-------|
| VCC | Supply voltage range |                                      | 2.8 |     | 5.5 | V     |
| Icc | Quiescent current    | INHIBIT = 0 V, V <sub>CC</sub> = 5 V |     | 15  |     | mA    |

NOTE 2: Ensured by design, not production tested.

#### reference/voltage identification

|           | PARAMETER                      | TEST CONDITIONS | MIN                       | TYP | MAX                   | UNITS |
|-----------|--------------------------------|-----------------|---------------------------|-----|-----------------------|-------|
| VID0-VID1 | High-level input voltage (2)   |                 | V <sub>BIAS</sub> - 0.3 V |     |                       | V     |
| VID0-VID1 | Mid-level floating voltage (1) |                 | $\frac{V_{BIAS}}{2} - 1$  | _   | <sup>/</sup> BIAS + 1 | V     |
| VID0-VID1 | Low-level input voltage (0)    |                 |                           |     | 0.3                   | V     |
|           | Input pull-to-mid resistance   |                 | 36.5                      | 73  | 95                    | kΩ    |

#### cumulative reference

| PARAMETER                            | TES                                                                 | ST CONDITIONS                                             |                            | MIN   | TYP   | MAX  | UNITS |
|--------------------------------------|---------------------------------------------------------------------|-----------------------------------------------------------|----------------------------|-------|-------|------|-------|
| Cumulative accuracy ripple regulator | V <sub>REF</sub> = 1.3 V,<br>T <sub>J</sub> = 25°C                  | Hysteresis window = 30 mV,                                |                            | -1.3% | 0.25% | 1.3% |       |
|                                      | V <sub>REF</sub> = 1.3 V,<br>T <sub>J</sub> = -40°C,                | Hysteresis wind<br>See Note 2                             | ow = 30 mV,                |       | -0.2% |      |       |
|                                      | V <sub>REF</sub> = full range,<br>Droop = 0,                        | Hysteresis window = 30 mV,<br>See Note 2                  |                            | -1.5% |       | 1.5% |       |
| Cumulative accuracy LDO              | V <sub>REF</sub> = 1.3 V,<br>Closed Loop,<br>T <sub>J</sub> = 25°C, | I <sub>O</sub> = 0.1 A,<br>Pass device = IF<br>See Note 2 | RFZ24N,                    | -2%   |       | 2%   |       |
|                                      | V <sub>REF</sub> = full range,<br>Pass device = IRFZ24              | I <sub>O</sub> = 0.1 A,<br>N,                             | Closed Loop,<br>See Note 2 | -2.5% |       | 2.5% | ·     |

NOTE 2. Ensured by design, not production tested.

#### buffered reference

| PARAMETER             |                                                      | MIN                                               | TYP                       | MAX                    | UNITS                     |   |
|-----------------------|------------------------------------------------------|---------------------------------------------------|---------------------------|------------------------|---------------------------|---|
|                       | I <sub>REFB</sub> =50 μA,                            | Accuracy from V <sub>REF</sub> nominal            | V <sub>REF</sub><br>-1.5% | V <sub>REF</sub>       | V <sub>REF</sub><br>+1.5% | V |
| VREFB output voltage  | I <sub>REFB</sub> =50 μA,<br>T <sub>J</sub> = -40°C, | Accuracy from V <sub>REF</sub> nominal See Note 2 |                           | V <sub>REF</sub> -0.6% |                           | V |
| VREFB load regulation | 10 μA < I <sub>REFB</sub> < 500 μA 2                 |                                                   | mV                        |                        |                           |   |

NOTE 2. Ensured by design, not production tested.

#### hysteretic comparator(ripreg)

| PARAMETER                                                                  | TEST CONDITIONS                                                    |      | TYP | MAX | UNITS |
|----------------------------------------------------------------------------|--------------------------------------------------------------------|------|-----|-----|-------|
| Input bias current                                                         | See Note 2                                                         |      |     | 500 | nA    |
| Hysteresis accuracy                                                        | VVREFB - VVHYST = 15 mV,<br>Hysteresis window = 30 mV              | -3.5 |     | 3.5 | mV    |
| Maximum hysteresis setting                                                 | VVREFB - VVHYST = 30 mV,<br>See Note 2                             | 60   |     |     | mV    |
| Propagation delay time from VSENSE to HIGHDR or LOWDR (excluding deadtime) | 10 mV overdrive, 1.3 V <= V <sub>REF</sub> <= 3.3 V,<br>See Note 2 |      | 150 | 250 | ns    |
| Prefilter pole frequency                                                   | See Note 2                                                         |      | 5   |     | MHz   |

NOTE 2. Ensured by design, not production tested.



# electrical characteristics $T_J$ = $0^{\circ}$ to $125^{\circ}$ C, $V_{CC}$ = 2.8 V to 5.5 V (unless otherwise noted) (continued)

#### overvoltage protection

| PARAMETER                                                        | TEST CONDITIONS                                 | MIN  | TYP | MAX | UNITS             |
|------------------------------------------------------------------|-------------------------------------------------|------|-----|-----|-------------------|
| OVP ripple regulator trip point (RR)                             | Upper threshold                                 | 112  | 115 | 120 | %V <sub>REF</sub> |
| Hysteresis (RR)                                                  | Upper threshold – lower threshold, (see Note 2) |      | 10  |     | mV                |
| Comparator propagation delay time (RR)                           | Voverdrive = 30 mV, See Note 2                  |      | 1   |     | μs                |
| Deglitch time (includes comparator propagation delay time) (RR)  | V <sub>overdrive</sub> = 30 mV, See Note 2      | 2.25 |     | 11  | μs                |
| OVP LDO trip point (LDO)                                         | Upper threshold                                 | 112  | 115 | 120 | %V <sub>REF</sub> |
| Hysteresis (LDO)                                                 | Upper threshold – lower threshold, (see Note 2) |      | 10  |     | mV                |
| Comparator propagation delay time (LDO)                          | V <sub>overdrive</sub> = 50 mV, See Note 2      |      | 1   |     | μs                |
| Deglitch time (includes comparator propagation delay time) (LDO) | Voverdrive = 50 mV, See Note 2                  | 2.25 |     | 11  | μs                |

NOTE 2. Ensured by design, not production tested.

#### undervoltage protection

| PARAMETER                                                        | CONDITIONS                                      | MIN | TYP | MAX | UNITS             |
|------------------------------------------------------------------|-------------------------------------------------|-----|-----|-----|-------------------|
| UVP ripple regulator trip point (RR)                             | Lower threshold                                 | 70  | 75  | 80  | %V <sub>REF</sub> |
| Hysteresis (RR)                                                  | Upper threshold – lower threshold, (see Note 2) |     | 10  |     | mV                |
| Comparator propagation delay time (RR)                           | V <sub>overdrive</sub> = 50 mV, See Note 2      |     | 1   |     | μs                |
| Deglitch time (includes comparator propagation delay time) (RR)  | V <sub>overdrive</sub> = 50 mV, See Note 2      | 0.1 |     | 1   | ms                |
| UVP LDO trip point (LDO)                                         | Lower threshold                                 | 70  | 75  | 80  | %V <sub>REF</sub> |
| Hysteresis (LDO)                                                 | Upper threshold – lower threshold, (see Note 2) |     | 10  |     | mV                |
| Comparator propagation delay time (LDO)                          | Voverdrive = 50 mV, See Note 2                  |     | 1   |     | μs                |
| Deglitch time (includes comparator propagation delay time) (LDO) | V <sub>overdrive</sub> = 50 mV, See Note 2      | 0.1 |     | 1   | ms                |

NOTE 2. Ensured by design, not production tested.

#### inhibit comparator

| PARAMETER       |                         | CONDITIONS | MIN  | TYP | MAX  | UNITS |
|-----------------|-------------------------|------------|------|-----|------|-------|
| Start threshold |                         |            |      | 2.1 | 2.35 | \/    |
|                 | T <sub>J</sub> = −40°C, | See Note 2 |      | 2.1 |      | ľ     |
| Stop threshold  |                         |            | 1.79 |     |      | V     |

NOTE 2. Ensured by design, not production tested.

#### **VDRV UVLO**

| PARAMETER       | CONDITIONS | MIN | TYP  | MAX | UNITS |
|-----------------|------------|-----|------|-----|-------|
| Start threshold | See Note 2 |     |      | 4.9 | V     |
| Hysteresis      | See Note 2 | 0.3 | 0.35 |     | V     |
| Stop threshold  | See Note 2 | 4.4 |      |     | V     |

NOTE 2. Ensured by design, not production tested.



# **TPS56302 DUAL-OUTPUT LOW-INPUT-VOLTAGE** DSP POWER SUPPLY CONTROLLER WITH SEQUENCING

SLVS289 - MARCH 2000

# electrical characteristics $T_J = 0^{\circ}$ to $125^{\circ}$ C, $V_{CC} = 2.8$ V to 5.5 V (unless otherwise noted) (continued)

#### slow-start

| PARAMETER                       | CONDITIONS                                                                                                               | MIN  | TYP | MAX  | UNITS |
|---------------------------------|--------------------------------------------------------------------------------------------------------------------------|------|-----|------|-------|
| Charge current                  | V(S/S) = 0.5  V,<br>Resistance from VREFB pin to ANAGND = 20 k $\Omega$<br>VREFB = 1.3 V, Ichg = (I <sub>VREFB</sub> /5) | 10.4 | 13  | 15.6 | μА    |
| Discharge current               | V(S/S) = 1.3 V                                                                                                           | 3    |     |      | mA    |
| Comparator input offset voltage |                                                                                                                          |      |     | 10   | mV    |
| Comparator input bias current   | See Note 2                                                                                                               |      | 10  | 100  | nA    |
| Hysteresis accuracy             |                                                                                                                          | -7.5 |     | 7.5  | mV    |
| Comparator propagation delay    | Overdrive = 10 mV, See Note 2                                                                                            |      | 560 | 1000 | ns    |

NOTE 2. Ensured by design, not production tested.

#### **VCC UVLO**

| PARAMETER       | CONDITIONS                        |      | TYP  | MAX  | UNITS |
|-----------------|-----------------------------------|------|------|------|-------|
| Stort throubold | (see Note 2)                      |      | 2.72 | 2.80 | V     |
| Start threshold | $T_J = -40^{\circ}C$ , See Note 2 |      | 2.71 |      | V     |
| Stop threshold  | (see Note 2)                      | 2.48 |      |      | V     |

NOTE 2. Ensured by design, not production tested.

#### power good

| PARAMETER                                                          | CONDITIONS                                     | MIN | TYP | MAX  | UNITS             |
|--------------------------------------------------------------------|------------------------------------------------|-----|-----|------|-------------------|
| Undervoltage trip point ripple regulator                           | VIN and VDRV above UVLO thresholds             | 90  | 93  | 95   | 9/\/              |
| (VSENSE-RR)                                                        | $T_J = -40^{\circ}C$ , See Note 2              |     | 93  |      | <sup>%V</sup> REF |
| Undervoltage trip point LDO                                        | V <sub>IN</sub> and VDRV above UVLO thresholds | 90  | 93  | 95   | 9/\/              |
| (VSENSE-LDO)                                                       | $T_J = -40^{\circ}C$ , See Note 2              |     | 93  |      | %VREF             |
| Output saturation voltage                                          | I <sub>O</sub> =5 mA                           |     | 0.5 | 0.75 | V                 |
| Leakage current                                                    | V <sub>PGD</sub> = 4.5 V                       |     | 1   |      | μΑ                |
| Hysteresis                                                         | V <sub>REF</sub> = 1.3 V, 1.5 V, or 1.8 V      |     | 50  | 75   | mV                |
| nysteresis                                                         | V <sub>REF</sub> = 2.5 V, or 3.3 V             |     | 100 | 125  | mV                |
| Comparator high–low transition time (propagation delay only)       | See Note 2                                     |     | 1   |      | μs                |
| Comparator low–high transition time (propagation delay + deglitch) | See Note 2                                     | 0.2 | 1   | 2    | ms                |

NOTE 2. Ensured by design, not production tested.

#### droop compensation

| PARAMETER        | CONDITIONS                  | MIN | TYP MAX | UNITS |
|------------------|-----------------------------|-----|---------|-------|
| Initial accuracy | $V_{DROOP} = 50 \text{ mV}$ | 46  | 54      | mV    |

#### overcurrent protection (RR)

| PARAMETER                                                  | CONDITIONS                                 |      | TYP | MAX | UNITS |
|------------------------------------------------------------|--------------------------------------------|------|-----|-----|-------|
| OCP trip point                                             |                                            | 118  | 130 | 142 | mV    |
| Input bias current                                         |                                            |      |     | 300 | nA    |
| Comparator propagation delay time                          | Voverdrive = 30 mV, See Note 2             |      | 1   |     | μs    |
| Deglitch time (includes comparator propagation delay time) | V <sub>overdrive</sub> = 30 mV, See Note 2 | 2.25 |     | 11  | μs    |



# electrical characteristics T $_J$ = 0 $^\circ$ to 125 $^\circ$ C, V $_{CC}$ = 2.8 V to 5.5 V (unless otherwise noted) (continued)

#### high-side VDS sensing

| PARAMETER                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                     | COND                                                                                      | ITIONS                              | MIN  | TYP | MAX  | UNITS |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------|-------------------------------------|------|-----|------|-------|
| Gain                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |                                                                                           |                                     |      | 2   |      | V/V   |
| Initial accuracy                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | VHISENSE = 3.3 V,<br>Differential input to Vds sensi                                      | VIOUTLO = 3.2 V,<br>ng amp = 100 mV | 194  |     | 208  | mV    |
| Common-mode rejection ratio                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                   | VHISENSE=2.8 V to 5.5 V,<br>VHISENSE- VIOUTLO=100                                         | mV                                  | 69   | 75  |      | dB    |
| Sink current (IOUTLO)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         | 2.8 V < V <sub>IOUTLO</sub> < 5.5 V                                                       |                                     |      |     | 250  | nA    |
| Source current (IOUT)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                         | V <sub>IOUT</sub> = 0.5 V,<br>V <sub>IOUTLO</sub> =2.8 V                                  | VHISENSE=3.3 V,                     | 500  |     |      | μΑ    |
| Sink current (IOUT)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | V <sub>IOUT</sub> = 0.05 V,<br>V <sub>IOUTLO</sub> =3.3 V                                 | VHISENSE=3.35 V,                    | 50   |     |      | μΑ    |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE=5.5 V,                                                                           | $R_{IOUT} = 10 \text{ k}\Omega$     | 0    |     | 1.75 |       |
| Output voltage swing                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | V <sub>HISENSE</sub> =4.5 V,                                                              | R <sub>IOUT</sub> = 10 kΩ           | 0    |     | 1.5  | V     |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE=3 V,                                                                             | R <sub>IOUT</sub> = 10 kΩ           | 0    |     | 0.75 |       |
| LOSENSE high-level input voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | V <sub>HISENSE</sub> =2.8 V,                                                              | See Note 2                          | 1.77 |     |      | V     |
| LOSENSE low-level input voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE=2.8 V,                                                                           | See Note 2                          |      |     | 1.49 | V     |
| LOSENSE high-level input voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | V <sub>HISENSE</sub> =4.5 V,                                                              | See Note 2                          | 2.85 |     |      | V     |
| LOSENSE low-level input voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE=4.5 V,                                                                           | See Note 2                          |      |     | 2.4  | V     |
| LOSENSE high-level input voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | V <sub>HISENSE</sub> =5.5 V,                                                              | See Note 2                          | 3.80 |     |      | V     |
| LOSENSE low-level input voltage                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | V <sub>HISENSE</sub> =5.5 V,                                                              | See Note 2                          |      |     | 3.2  | V     |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE = 6 V,                                                                           | See Note 2                          | 70   |     | 90   |       |
| On any latter and the state of | VHISENSE = 4.5 V,                                                                         | See Note 2                          | 80   |     | 100  |       |
| Sample/hold resistance                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        | VHISENSE = 3.6 V,                                                                         | See Note 2                          | 90   |     | 120  | Ω     |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE = 2.8 V,                                                                         | See Note 2                          | 120  |     | 180  |       |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE = 2.55 V,<br>VIOUTLO pulsed from 2.55 V<br>100 ns rise and fall times,           | to 2.45 V,<br>See Note 2            |      |     | 4    |       |
| Response time (measured from 90% of                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           | VHISENSE = 2.8 V,<br>V <sub>IOUTLO</sub> pulsed from 2.8 V<br>100 ns rise and fall times, | to 2.7 V,<br>See Note 2             |      |     | 3.5  |       |
| VIOUTLO to 90% of VIOUT)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | VHISENSE = 4.5 V,<br>V <sub>IOUTLO</sub> pulsed from 4.5 V<br>100 ns rise and fall times, | to 4.4 V,<br>See Note 2             |      |     | 3    | μs    |
|                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               | VHISENSE = 5.5 V,<br>V <sub>IOUTLO</sub> pulsed from 5.5 V<br>100 ns rise and fall times, | to 5.9 V,<br>See Note 2             |      |     | 3    |       |
| Short circuit protection rising edge delay                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    | LOSENSE grounded,                                                                         | See Note 2                          | 300  |     | 500  | ns    |
| Sample/hold switch turnon/turnoff delay                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       | 2.8 V < VHISENSE < 5.5 V,<br>VLOSENSE = VHISENSE,                                         | See Note 2                          | 30   |     | 100  | ns    |



# TPS56302 DUAL-OUTPUT LOW-INPUT-VOLTAGE DSP POWER SUPPLY CONTROLLER WITH SEQUENCING

SLVS289 - MARCH 2000

# electrical characteristics $T_J$ = $0^\circ$ to $125^\circ C$ , $V_{CC}$ = 2.8 V to 5.5 V (unless otherwise noted) (continued)

#### thermal shutdown

| PARAMETER                   | CONDITIONS | MIN | TYP | MAX | UNITS |
|-----------------------------|------------|-----|-----|-----|-------|
| Over temperature trip point | See Note 2 | 145 |     |     | °C    |
| Hysteresis                  | See Note 2 |     | 10  |     | °C    |

NOTE 2. Ensured by design, not production tested.

#### synch charge pump regulator

| PARAMETER                             | CONDITIONS                                     |                                         | MIN  | TYP | MAX | UNITS |
|---------------------------------------|------------------------------------------------|-----------------------------------------|------|-----|-----|-------|
| Internal oscillator frequency         | 2.8 V < V <sub>IN</sub> < 5.5 V,<br>VDRV=5 V , | I <sub>DRV</sub> = 50 mA,<br>See Note 2 | 200  | 300 | 400 | kHz   |
| Internal oscillator turnon threshold  | V <sub>CC</sub> above UVLO threshold,          | See Note 2                              | 5.05 | 5.2 |     | V     |
| Internal oscillator turnon hysteresis | V <sub>CC</sub> above UVLO threshold,          | See Note 2                              |      |     | 20  | mV    |

NOTE 2. Ensured by design, not production tested.

#### hysteretic comparator (charge pump)

| PARAMETER  | CONDITIO                                         | MIN        | TYP  | MAX | UNITS |    |
|------------|--------------------------------------------------|------------|------|-----|-------|----|
| Threshold  | V <sub>IN</sub> above UVLO threshold, See Note 2 |            | 5.05 | 5.2 |       | V  |
| Hysteresis | V <sub>IN</sub> above UVLO threshold,            | See Note 2 |      |     | 20    | mV |

NOTE 2. Ensured by design, not production tested.

#### deadtime circuit

| PARAMETER                              | CONDITIONS                                       | MIN | TYP | MAX  | UNITS |
|----------------------------------------|--------------------------------------------------|-----|-----|------|-------|
| LOSENSE/LOHIB high level input voltage | V <sub>HISENSE</sub> =2.55 V – 5.5 V, See Note 2 | 2.4 |     |      | V     |
| LOSENSE/LOHIB low level input voltage  | V <sub>HISENSE</sub> =2.55 V – 5.5 V, See Note 2 |     |     | 1.33 | V     |
| LOWDR high level input voltage         | V <sub>HISENSE</sub> =2.55 V–5.5 V, See Note 2   | 3   |     |      | V     |
| LOWDR low level input voltage          | VHISENSE=2.55 V-5.5 V, See Note 2                |     |     | 1.7  | V     |
| Driver nonoverlap time                 | CLOWDR = 9 nF, 10% threshold on LOWDR, VDRV=5 V  | 40  |     | 170  | ns    |



# electrical characteristics $T_J = 0^\circ$ to $125^\circ C$ , $V_{CC} = 2.8 \text{ V}$ to 5.5 V (unless otherwise noted) (continued)

#### output drivers (see Note 5)

| PARAMETER                          | CONDITIONS                                                                                                                                                                                                                                                                         | MIN | TYP | MAX | UNITS |  |  |
|------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|-------|--|--|
|                                    | $\label{eq:Duty cycle} \begin{array}{ll} \text{Duty cycle} < 2\%, & t_{\text{DW}} < 100 \text{ us}, \\ \text{VBOOT} - \text{VBOOTLO} = 4.5 \text{ V}, \\ \text{VHIGHDR} = 4 \text{ V (sink)}, & \text{See Note 2 and Figure 15} \end{array}$                                       | 0.7 | 2   |     |       |  |  |
| Peak output current                | $\label{eq:Duty cycle} \begin{array}{ll} \text{Duty cycle} < 2\%, & t_{\text{DW}} < 100 \text{ us}, \\ \text{V}_{\text{BOOT}} - \text{V}_{\text{BOOTLO}} = 4.5 \text{ V}, \\ \text{V}_{\text{HIGHDR}} = 0.5 \text{ V (source)}, & \text{See Note 2 and Figure 15} \end{array}$     | 1.2 | 2   |     | A     |  |  |
|                                    | $\begin{array}{ll} \text{Duty cycle} < 2\%, & \text{$t_{pW}$} < 100~\mu\text{s}, \\ \text{$V_{DRV}$} = 4.5~\text{V}, & \text{$V_{LOWDR}$} = 4~\text{V (sink)}, \\ \text{See Note 2 and Figure 15} & \end{array}$                                                                   | 1.3 | 2   |     | A     |  |  |
|                                    | $\begin{array}{ll} \mbox{Duty cycle} < 2\%, & \mbox{$t_{pW}$} < 100 \mbox{ us}, \\ \mbox{$V_{DRV}$} = 4.5 \mbox{ V}, & \mbox{$V_{LOWDR}$} = 0.5 \mbox{ V} \mbox{ (source)}, \\ \mbox{See Note 2 and Figure 15} & \mbox{$v_{LOWDR}$} = 0.5 \mbox{ V} \mbox{ (source)}, \end{array}$ | 1.4 | 2   |     |       |  |  |
|                                    | VBOOT - VBOOTLO = 4.5 V, VHIGHDR = 0.5 V,<br>See Note 2                                                                                                                                                                                                                            | !   |     | 5   |       |  |  |
| Output resistance                  | VBOOT - VBOOTLO = 4.5 V, VHIGHDR = 4 V,<br>See Note 2                                                                                                                                                                                                                              |     |     | 45  | Ω     |  |  |
|                                    | $V_{DRV} = 4.5 \text{ V}, \qquad V_{LOWDR} = 0.5 \text{ V},  \text{See Note 2}$                                                                                                                                                                                                    |     |     | 9   |       |  |  |
|                                    | $V_{DRV} = 4.5 \text{ V}, \qquad V_{LOWDR} = 4 \text{ V}, \qquad \text{See Note 2}$                                                                                                                                                                                                |     |     | 45  | 1     |  |  |
| HIGHDR rise/fall time              | $C_L = 3.3 \text{ nF}, V_{BOOT} = 4.5 \text{ V}, V_{BOOTLO} = \text{grounded}, See \text{ Note 2}$                                                                                                                                                                                 |     |     | 60  | ns    |  |  |
| LOWDR rise/fall time               | $C_L = 3.3 \text{ nF}, \qquad V_{DRV} = 4.5 \text{ V}, \qquad \text{See Note 2}$                                                                                                                                                                                                   |     |     | 40  | ns    |  |  |
|                                    | INHIBIT grounded, $V_{IN} < UVLO, V_{BOOT}=6 V,$ BOOTLO grounded                                                                                                                                                                                                                   |     |     | 10  | μΑ    |  |  |
| High-side driver quiescent current | $\begin{array}{llllllllllllllllllllllllllllllllllll$                                                                                                                                                                                                                               |     | 2   |     | mA    |  |  |

NOTES: 2. Ensured by design, not production tested.

#### **LDO N-channel output driver**

| PARAMETER                                        | CONDITIONS                                                                                                |                                                   |              | TYP | MAX | UNITS       |
|--------------------------------------------------|-----------------------------------------------------------------------------------------------------------|---------------------------------------------------|--------------|-----|-----|-------------|
| Peak output current                              | VLDODRV = 7.5 V,<br>VIOSENSE = 0.9 × VLDOREF,                                                             | V <sub>N-DRV</sub> = 3 V (source),<br>See Note 2  | 100          |     |     | μΑ          |
|                                                  | V <sub>LDODRV</sub> = 7.5 V,<br>V <sub>IOSENSE</sub> = 1.1 × V <sub>LDOREF</sub> ,                        | V <sub>N-DRV</sub> =0 V (sink),<br>See Note 2     | 1.5          |     |     | mA          |
| Open loop voltage gain (VNGATE-LDO / VSENSE-LDO) | 7.5 V $\geq$ V <sub>NGATE-LDO</sub> $\geq$ 0.5 V,<br>See Note 2                                           | $V_{IN} = 5.5 V,$                                 | 3000<br>(70) |     |     | V/V<br>(dB) |
| Power supply ripple rejection                    | $ f = 1 \text{ kHz}, \\ 5.5 \text{ V} \ge \text{V}_{\text{IN}} \ge 2.55 \text{ V}, \\ \text{See Note 2} $ | C <sub>O</sub> =10 μF,<br>T <sub>J</sub> =125 °C, | 60           |     |     | dB          |



<sup>5.</sup> The pullup/pulldown circuits of the drivers are bipolar and MOSFET transistors in parallel. The peak output current rating is the combined current from the bipolar and MOSFET transistors. The output resistance is the R<sub>ds(on)</sub> of the MOSFET transistor when the voltage on the driver output is less than the saturation voltage of the bipolar transistor.

## TPS56302 DUAL-OUTPUT LOW-INPUT-VOLTAGE DSP POWER SUPPLY CONTROLLER WITH SEQUENCING

SLVS289 - MARCH 2000

#### electrical characteristics $T_J = 0^\circ$ to 125°C, $V_{CC} = 2.8 \text{ V}$ to 5.5 V (unless otherwise noted) (continued)

#### V<sub>SENSE-RR</sub> and V<sub>SENSE-LDO</sub> discharge

| PARAMETER                                                          | CONDITIO            | NS                 | MIN | TYP | MAX | UNITS |
|--------------------------------------------------------------------|---------------------|--------------------|-----|-----|-----|-------|
| VSENSE-RR discharge FET current saturation                         | VSENSE-RR = 1.5 V,  | See Note 2         |     | 5   |     | mA    |
| V <sub>SENSE-RR</sub> discharge series resistance (limits current) | INHIBIT = 0 V,      | $V_{1N} = 5.5 V$   |     | 1   |     | kΩ    |
| V <sub>SENSE-RR</sub> discharge FET propagation delay time         | See Note 2          |                    |     |     | 100 | ns    |
| VSENSE-LDO discharge FET current saturation                        | VSENSE-LDO = 3.3 V, | See Note 2         |     | 5   |     | mA    |
| VSENSE-LDO discharge series resistance (limits current)            | INHIBIT = 0 V,      | $V_{IN} = 5.5 V$ , |     | 1   |     | kΩ    |
| VSENSE-LDO discharge FET propagation delay time                    | See Note 2          |                    |     |     | 100 | ns    |

NOTE 2. Ensured by design, not production tested.

#### detailed description

#### reference/voltage identification

The reference/voltage identification definition (VID) section consists of a temperature compensated bandgap reference and a 2-pin voltage selection network. Both ripple regulator and LDO reference voltages are programmed with each VID setting. The 2 VID pins are inputs to the VID selection network and are tri-level inputs that may be set to GND, floating ( $V_{BIAS}$ /2), or  $V_{BIAS}$ . The VID codes allow the controller to power both current and future DSP products. The output voltages may also be programmed by external resistor voltage dividers for any values not included in the VID code settings. Refer to Table 1 for the VID code settings. The output voltages of the VID network,  $V_{REF-RR}$ , is within 1.5% and  $V_{REF-LDO}$  is within 2.5% of the nominal setting over the VID range of 1.3 V to 3.3 V. The reference tolerance conditions include a junction temperature range of  $-40^{\circ}$ C to  $+125^{\circ}$ C and a  $V_{CC}$  supply voltage range of 2.8 V to 5.5 V. The  $V_{REF-RR}$  output of the reference/VID network is indirectly brought out through a buffer to the VREFB pin. The voltage on this pin will be within 1.5% of  $V_{REF-RR}$ . It is not recommended to drive loads with VREFB, other than setting the hysteresis of the hysteretic comparator, because the current drawn from VREFB sets the charging current for the slow-start capacitor. Refer to the Slow-start section of this document for additional information.

#### hysteretic comparator

The hysteretic comparator regulates the output voltage of the synchronous-buck converter. The hysteresis is set by 2 external resistors and is centered around  $V_{REF}$ . The two external resistors form a resistor divider from VREFB to ANAGND, and the divided down voltage connects to the VHYST pin. The hysteresis of the comparator will be equal to twice the voltage difference that is across the VREFB and VHYST pins. The propagation delay from the comparator inputs to the driver outputs is 250 ns maximum. The maximum hysteresis setting is 60 mV.

#### low-side driver

The low-side driver is designed to drive low  $r_{DS(on)}$  logic-level N-channel MOSFETs. The current rating of the driver is 2-A typical, source and sink. The bias to the low-side driver is internally connected to the regulated synchronous charge pump output.

#### high-side driver

The high-side driver is designed to drive low r<sub>DS(on)</sub> logic-level N-channel MOSFETs. The current rating of the driver is 2 amps typical, source and sink. The high-side driver can be configured either as a floating bootstrap driver or as a ground-reference driver. When configured as a floating driver, the bias voltage to the driver is developed from the charge pump VDRV voltage. The internal synchronous bootstrap rectifier, connected between the VDRV and BOOT pins, is a synchronously-rectified MOSFET for improved drive efficiency. The maximum voltage that can be applied between the BOOT pin and ground is 14 V.



#### detailed description (continued)

#### deadtime control

Deadtime control prevents shoot-through current from flowing through the main power FETs during switching transitions by actively controlling the turnon time of the MOSFET drivers. The high-side driver is not allowed to turn on until the gate drive voltage to the low-side FET is below 1 V, and the low-side driver is not allowed to turn on until the voltage at the junction of the 2 FETs (Vphase) is below 2 V.

#### current sensing

Current sensing is achieved by sampling and holding the voltage across the high-side power FET while the high-side FET is on. The sampling network consists of an internal  $60-\Omega$  switch and an external hold capacitor. Internal logic controls the turnon and turnoff of the sample/hold switch such that the switch does not turn on until the Vphase voltage transitions high, and the switch turns off when the input to the high-side driver goes low. Thus sampling will occur only when the high-side FET is conducting current. The voltage on the IOUT pin equals 2 times the sensed high-side voltage.

#### droop compensation

The droop compensation network reduces the load transient overshoot / undershoot on  $V_{OUT}$ , relative to  $V_{REF}$  (see the *application information* section of this document for more details).  $V_{OUT}$  is programmed to a voltage greater than  $V_{REF}$  by an external resistor divider from  $V_{OUT}$  to the VSENSE pin to reduce the undershoot on  $V_{OUT}$  during a low to high load transient. The overshoot during a high to low load transient is reduced by subtracting the voltage that is on the DROOP pin from  $V_{REF}$ . The voltage on the IOUT pin is divided down with an external resistor divider, and connected to the DROOP pin.

#### inhibit

INHIBIT is a TTL-compatible comparator pin that is used to enable the controller. When INHIBIT is lower than the threshold, the output drivers are low and the slow-start capacitor is discharged. When INHIBIT goes high (above 2.1 V), the short across the slow-start capacitor is released and normal converter operation begins. When another system logic supply is connected to the INHIBIT pin, this pin controls power sequencing by locking out controller operation until the system logic supply exceeds the input threshold voltage of the inhibit circuit; thus the +3.3-V supply and another system logic supply (either +5 V or +12 V) must be above UVLO thresholds before the controller is allowed to start up. Toggling the INHIBIT pin from low to high or recycling  $V_{CC}$  clears the fault latch.

#### slow-start

The slow-start circuit controls the rate at which both  $V_{OUT-RR}$  and  $V_{OUT-LDO}$  power up (at the same time). A capacitor is connected between the SLOWST and ANAGND pins and is charged by an internal current source. The value of the current source is proportional to the reference voltage, so that the charging rate of  $C_{SLOWST}$  is proportional to the ripple regulator reference voltage. The slow-start charging current is determined by the following equation:

$$I_{SLOWSTART} = \frac{I_{VREFB}}{5}$$

Where  $I_{VREFB}$  is the current flowing out of the VREFB pin. It is recommended that no additional loads be connected to VREFB, other than the resistor divider for setting the hysteresis voltage. Thus these resistor values will determine the slow-start charging current. The maximum current that can be sourced by the VREFB circuit is 500  $\mu$ A. The equation for the slow-start time is:

$$T_{SLOWSTART} = 5 \times C_{SLOWSTART} \times R_{VREFB}$$

Where R<sub>VREFB</sub> is the total external resistance from VREFB to ANAGND.



## TPS56302 DUAL-OUTPUT LOW-INPUT-VOLTAGE DSP POWER SUPPLY CONTROLLER WITH SEQUENCING

SLVS289 - MARCH 2000

#### detailed description (continued)

#### V<sub>CC</sub> and VDRV undervoltage lockout

The  $V_{CC}$  undervoltage lockout circuit disables the controller while the  $V_{CC}$  supply is below the 2.8-V start threshold. The VDRV undervoltage lockout circuit disables the controller while the VDRV supply is below the 4.9 V start threshold during powerup. While the controller is disabled, the output drivers will be low, the LDO drive is off, and the slow-start capacitor will be shorted. When  $V_{CC}$  and VDRV exceed the start threshold, the short across the slow-start capacitor is released and normal converter operation begins. Recycling  $V_{CC}$  or toggling the INHIBIT pin from low to high clears the fault latch.

#### power good

The power good circuit monitors for an undervoltage condition on  $V_{OUT-RR}$  and  $V_{OUT-LDO}$ . The power good (PWRGD) pin is pulled low if either  $V_{OUT-RR}$  is 7% below  $V_{REF-RR}$ , or  $V_{OUT-LDO}$  is 7% below  $V_{REF-LDO}$ . PWRGD is an open drain output. The PWRGD pin is also pulled down, if either  $V_{CC}$  or VDRV are below their UVLO thresholds.

#### overvoltage protection

The overvoltage protection circuit monitors  $V_{OUT-RR}$  and  $V_{OUT-LDO}$  for an overvoltage condition. If  $V_{OUT-RR}$  or  $V_{OUT-LDO}$  are 15% above their reference voltage, then a fault latch is set and both output drivers and LDO are turned off. The latch remains set until the  $V_{CC}$  or inhibit voltages go below their undervoltage lockout turnoff values. A 1- $\mu$ s to 5  $\mu$ s deglitch timer is included for noise immunity.

#### overcurrent protection

The overcurrent protection circuit monitors the current through the high-side FET. The overcurrent threshold is adjustable with an external resistor divider between IOUT and ANAGND pins, with the divider voltage connected to the OCP pin. If the voltage on the OCP pin exceeds 125 mV, a fault latch is then set and the output drivers are turned off. The latch remains set until the  $V_{CC}$  or inhibit voltages go below their undervoltage lockout values. A 1- $\mu$ s to 5- $\mu$ s deglitch timer is included for noise immunity. The OCP circuit is also designed to protect the high-side power FET against a short-to-ground fault on the terminal common to both power FETs.

#### undervoltage protection

The undervoltage protection circuit monitors  $V_{OUT-RR}$  and  $V_{OUT-LDO}$  for an undervoltage condition. If  $V_{OUT-RR}$  or  $V_{OUT-LDO}$  is 15% below their reference voltage, then a fault latch is set and both output drivers and LDO are turned off. The latch remains set until the  $V_{CC}$  or inhibit voltages go below their undervoltage lockout values. A 100- $\mu$ s to 1-ms deglitch timer is included for noise immunity.

#### synchronous charge pump

The regulated synchronous charge pump provides drive voltage to the low-side driver at VDRV (5 V), and to the high-side driver configured as a floating driver. The minimum drive voltage is 4.5 V, (typical is 5 V). The minimum short-circuit current is 80 mA. The bootstrap capacitor is used to provide voltage for the high-side FET, the power for VLDODRV, and the bias regulator. Instead of diodes, synchronous rectified MOSFETs are used to reduce voltage drop losses and allow a lower input voltage threshold. The charge pump oscillator operates at 300 kHz until the UVLO VDRV is set; after which it is synchronized to the converter switching frequency and is turned on and off to regulate VDRV at 5 V.

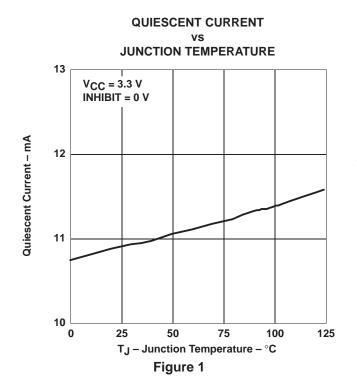
The charge pump is designed to operate at a switching frequency of 200 kHz to 400 kHz. Operation at low frequency may require larger capacitors on the CPCx and VDRV pins. Higher frequencies (> 400 kHz) may not be possible.

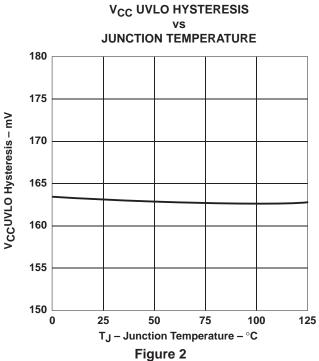
#### power sequence

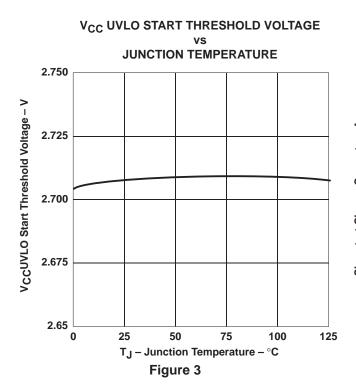
The  $V_{OUT-LDO}$  voltage is powered up with respect to the same slow-start reference voltage as the  $V_{OUT-RR}$  Also, at power down, the  $V_{OUT-RR}$  and  $V_{OUT-LDO}$  are discharged to ground through P-channel MOSFETs in series with 1-k $\Omega$  resistors.

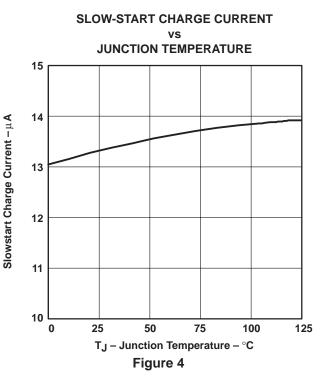


#### TYPICAL CHARACTERISTICS

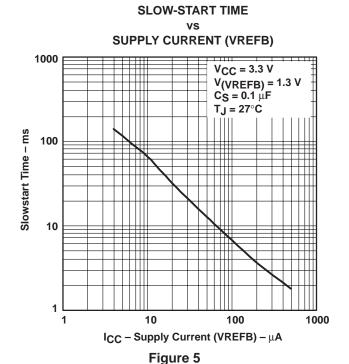


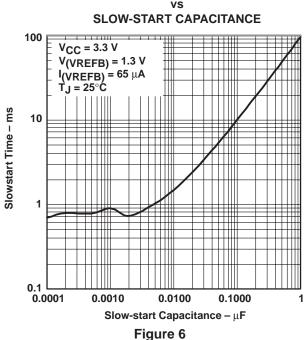




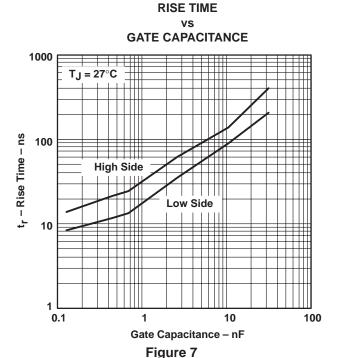


#### **TYPICAL CHARACTERISTICS**

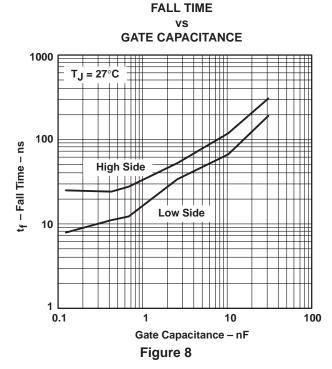




**SLOW-START TIME**<sup>†</sup>

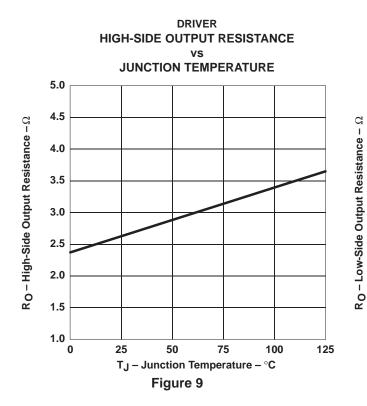


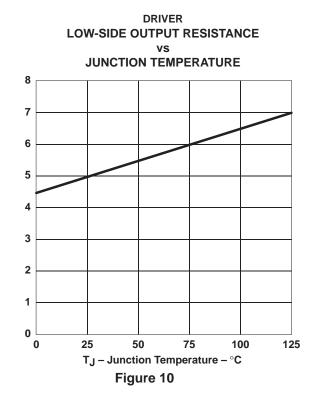
DRIVER

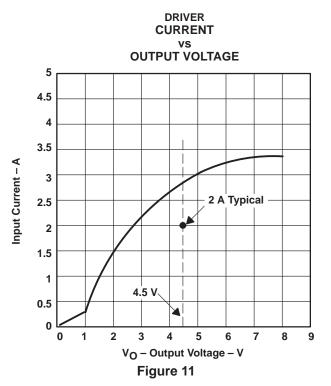


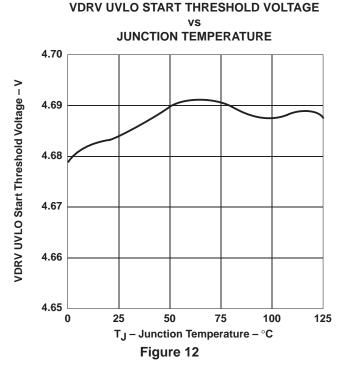
**DRIVER** 

#### TYPICAL CHARACTERISTICS

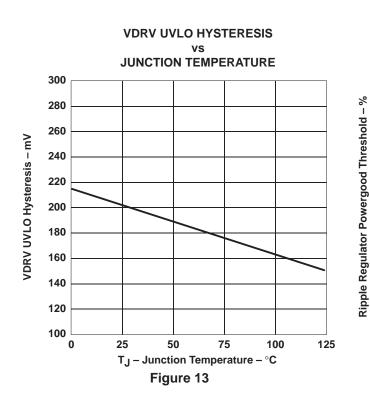


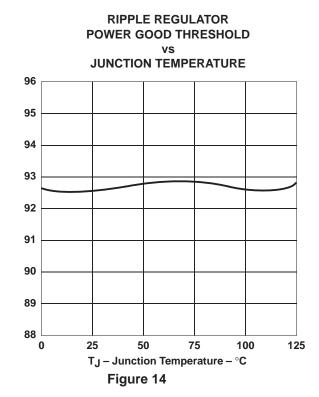


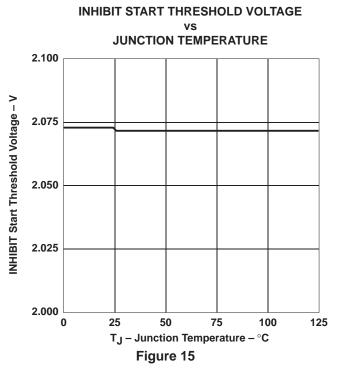


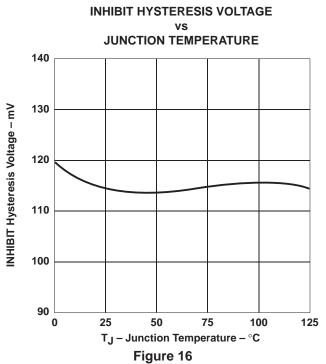


#### TYPICAL CHARACTERISTICS

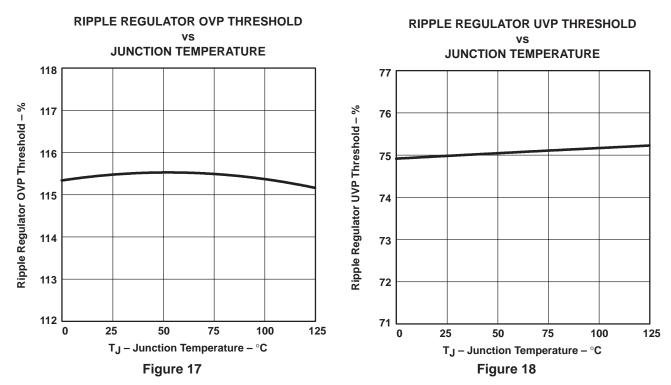








#### TYPICAL CHARACTERISTICS



# OCP THRESHOLD VOLTAGE VS JUNCTION TEMPERATURE 135 131 129 0 25 50 75 100 125 T<sub>J</sub> – Junction Temperature – °C



Figure 19

#### **TYPICAL CHARACTERISTICS**

# LDO OVP THRESHOLD vs JUNCTION TEMPERATURE

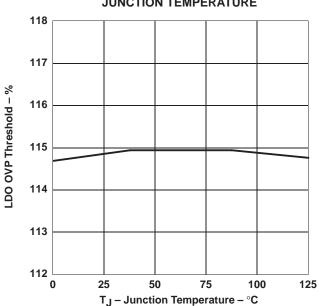


Figure 20

# LDO UVP THRESHOLD vs

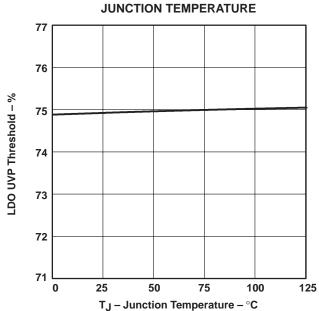


Figure 21



#### **APPLICATION INFORMATION**

#### evaluation module

In many DSP applications, the voltage bus powering DSP I/O also has to power peripheral circuitry. The total current is much higher than the requirement for the I/O only. This is the reason to use the high-efficiency ripple regulator to power I/O. In turn, the core power is delivered by LDO output. Since the I/O voltage is lower than the input voltage in cases such as 5-V input, but higher than the core voltage, the ripple regulator output should be used as the input voltage for LDO to achieve higher efficiency. In EVM testing, J1–4 (RR–OUT) is connected to J2–1(VI–LDO). The test results displayed in this section are all based on this configuration.

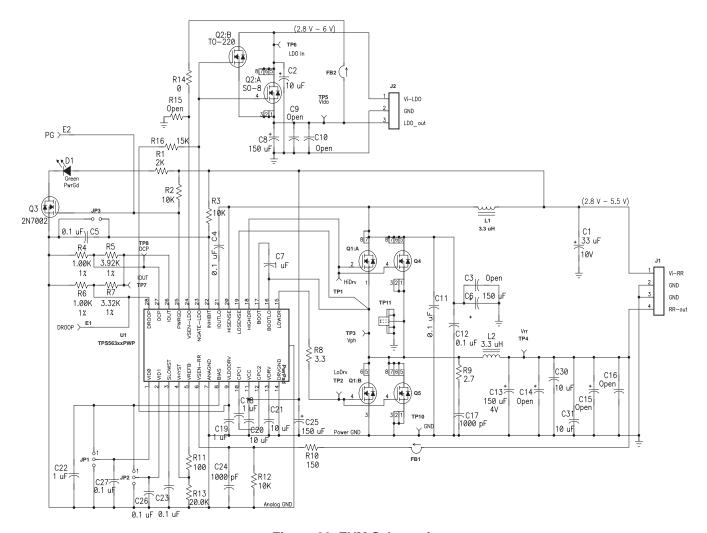


Figure 22. EVM Schematic

**Table 2. EVM Input and Outputs** 

| V <sub>IN</sub> | I <sub>IN</sub> | $V_{RR}$ | I <sub>RR</sub> | $V_{LDO}$ | I <sub>LDO</sub> |
|-----------------|-----------------|----------|-----------------|-----------|------------------|
| 5 V             | 4 A             | 3.3 V    | 4 A             | 1.8 V     | 0.5 A            |



#### **APPLICATION INFORMATION**

**Table 3. Ripple Regulator Power Stage Components** 

|                 |                            | 1                                                                                          | Ripple Regulator Section                                                                   |                                                                                             |                                                                                             |
|-----------------|----------------------------|--------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------|
| Ref Des         | Function                   | 4A (EVM Design)                                                                            | 8A <sup>†</sup>                                                                            | 12A <sup>†</sup>                                                                            | 20A†                                                                                        |
| C3, C6          | Input bulk capacitor       | C3: open<br>C6: 150 μF<br>(Sanyo,<br>6TPB150M)                                             | C3: 150 μF<br>C6: 150 μF<br>(Sanyo,<br>6TPB150M)                                           | C3: 150 μF<br>C6: 150 μF<br>(Sanyo,<br>6TPB150M)                                            | C3: 150 μF<br>C6: 2x150 μF<br>(Sanyo,<br>6TPB150M)                                          |
| C11, C2         | Input high-freq capacitor  | C2: 0.1 µF<br>C11: 0.1 µF<br>(muRata<br>GRM39X7R104K016A,<br>0.1 µF, 16–V, X7R)            | C2: 0.1 µF<br>C11: 0.1 µF<br>(muRata<br>GRM39X7R104K016A,<br>0.1 µF, 16–V, X7R)            | C2: 0.1 μF<br>C11: 0.1 μF<br>(muRata<br>GRM39X7R104K016A, 0.1<br>μF, 16–V, X7R)             | C2: 0.33 μF<br>C11: 0.33 μF<br>(muRata<br>GRM39X7R334K016A,<br>0.33 μF, 16–V, X7R)          |
| C13, C14        | Output bulk capacitor      | C13: 150 μF<br>(Sanyo, 6TPB150M)<br>C14: open                                              | C13: 150 μF<br>(Sanyo, 6TPB150M)<br>C14: open                                              | C13: 150 μF<br>C14: 150 μF<br>(Sanyo, 6TPB150M)                                             | C13: 150 μF<br>C14: 150 μF<br>(Sanyo, 6TPB150M)                                             |
| C15,C30,<br>C31 | Output mid-freq capacitor  | C15: open<br>C30: 10 µF<br>C31: 10 µF<br>(muRata<br>GRM39X7R106K016A,<br>10 µF, 16–V, X7R) | C15: open<br>C30: 10 µF<br>C31: 10 µF<br>(muRata<br>GRM39X7R106K016A,<br>10 µF, 16–V, X7R) | C15: 10 μF<br>C30: 10 μF<br>C31: 10 μF<br>(muRata<br>GRM39X7R106K016A, 10<br>μF, 16–V, X7R) | C15: 10 µF<br>C30: 10 µF<br>C31: 10 µF<br>(muRata<br>GRM39X7R106K016A,<br>10 µF, 16–V, X7R) |
| C16             | Output high-freq capacitor | open                                                                                       | 0.1 μF<br>(muRata<br>GRM39X7R104K016A,<br>0.1 μF, 16–V, X7R)                               | 0.1 μF<br>(muRata<br>GRM39X7R104K016A, 0.1<br>μF, 16–V, X7R)                                | 0.1 μF<br>(muRata<br>GRM39X7R104K016A,<br>0.1 μF, 16–V, X7R)                                |
| L1              | Input filter               | 3.3 µH<br>Coilcraft<br>DO3316P-332, 5.4 A                                                  | 3.3 μH<br>Coilcraft<br>DO3316P–332,5.4 A                                                   | 1.5 µH<br>Coilcraft<br>DO3316P–152,6.4 A                                                    | 1 μH<br>Coiltronics<br>UP3B–1R0, 12.5–A                                                     |
| L2              | Output filter              | 3.3 μH<br>Coilcraft<br>DO3316P–332, 5.4 A                                                  | 3.3 µH<br>Coilcraft<br>DO5022P–332HC, 10 A                                                 | 1.5 µH<br>Coilcraft<br>DO5022P–152HC,<br>15 A                                               | 3.3 µH<br>Micrometals,<br>T68–8/90 Core w/7T,<br>#16, 25 A                                  |
| R8              | Low side gate resistor     | 10 Ω                                                                                       | 10 Ω                                                                                       | 5.1 Ω                                                                                       | 5.1 Ω                                                                                       |
| Q1A,Q4          | Power switch               | Q1A: Dual FET<br>IRF7311                                                                   | Q4: IRF7811                                                                                | Q4: 2xIRF7811                                                                               | Q4: 2xIRF7811                                                                               |
| Q1B,Q5          | Synchronous switch         | Q1B: Dual FET<br>IRF7311                                                                   | Q5: IRF7811                                                                                | Q5: 2xIRF7811                                                                               | Q5:<br>2xIRF7811                                                                            |

<sup>†</sup> Position available on the EVM board

The values listed in Table 3 are recommendations based on actual test circuits. Many variations of the above are possible based upon the desires and/or requirements of the user. Performance of the circuit is equally, if not more, dependent upon the layout than on the specific components, as long as the device parameters are not exceeded. Fast-response, low-noise circuits require circuits require critical attention to the layout details.



#### **APPLICATION INFORMATION**

**Table 4. LDO Power Stage Components** 

| LDO Section |                                                               |                 |                           |                                                                                                            |  |  |  |
|-------------|---------------------------------------------------------------|-----------------|---------------------------|------------------------------------------------------------------------------------------------------------|--|--|--|
| Ref. Des    | Part                                                          | V <sub>IN</sub> | Vout                      | Description                                                                                                |  |  |  |
| Q2:A        | IRF7811(EVM)<br>or<br>Si4410, IRF7413 <sup>‡</sup><br>FDS6680 | VIN             | VIN-VDROPOUT <sup>†</sup> | Used as a power distribution switch for LDO output control                                                 |  |  |  |
| Q2:A        | IRF9410, Si9410 <sup>‡</sup>                                  |                 |                           | Low cost solution for low LDO output current (V <sub>IN</sub> -V <sub>OUT</sub> )*I <sub>OUT</sub> < 1 W   |  |  |  |
| Q2:A        | IRF7811 <sup>‡</sup>                                          |                 |                           | Higher current and still surface mount 1 W < (V <sub>IN</sub> -V <sub>OUT</sub> )*I <sub>OUT</sub> ) < 2 W |  |  |  |
| Q2: B       | IRLZ24N <sup>‡</sup>                                          |                 |                           | High output current requiring heat sink. Low cost but through–hole package. (VIN–VOUT)*IOUT > 2 W          |  |  |  |

TVDROPOUT = IOUT × RDSON. It should be as small as possible.

#### frequency calculation

With hysteretic control, the switching frequency is a function of the input voltage, the output voltage, the hysteresis window, the delay of the hysteresis comparator and the driver, the output inductance, the resistance in the output inductor, the output capacitance, the ESR and ESL in the output capacitor, the output current, and the turnon resistance of high-side and low-side MOSFET. It is a very complex equation if everything is included. To make it more useful to designers, a simplified equation is developed that considers only the most influential factors. The tolerance of the result for this equation is about 30%:

$$\mathsf{f_S} \ = \frac{\mathsf{V_{OUT}} \times \left(\mathsf{V_{IN}} - \mathsf{V_{OUT}}\right) \times \left(\mathsf{ESR} - \frac{\left(250 \times 10^{-9} + \mathsf{T_d}\right)}{\mathsf{C_{out}}}\right)}{\mathsf{V_{IN}} \times \left(\mathsf{V_{IN}} \times \mathsf{ESR} \times \left(250 \times 10^{-9} + \mathsf{T_d}\right) + \mathsf{V_{hys}} \times \mathsf{L_{OUT}} - \mathsf{ESL} \times \mathsf{V_{IN}}\right)}$$

Where  $f_S$  is the switching frequency (Hz);  $V_{OUT}$  is the output voltage (V);  $V_{IN}$  is the input voltage (V);  $C_{OUT}$  is the output capacitance; ESR is the equivalent series resistance in the output capacitor ( $\Omega$ ); ESL is the equivalent series inductance in the output capacitor (H);  $L_{OUT}$  is the output inductance (H);  $T_d$  is output feedback RC filter time constant (S);  $V_{hvs}$  is the hysteresis window (V).

#### output voltage setpoint calculation

In some applications, the required output voltage is different from the VID reference voltage. In this case, external voltage divider can be used for the setpoint adjustment. The voltage divider is composed of two resistors. The equation for the setpoint is:

$$R_{bottom} = \frac{R_{top} \times V_R}{V_O - V_R}$$

Where  $V_R$  is the reference voltage;  $V_O$  is the required output voltage setpoint.  $V_R$  should be lower than  $V_O$ . In EVM design, the top resistor is R14 for the LDO output, or R10 for ripple regular output; the bottom resistor is R15 for LDO output, or R12 for ripple regulator output.



<sup>‡</sup> Position available on the EVM board

#### APPLICATION INFORMATION

#### hysteresis window

The changeable hysteresis window in TPS56302 is used for switching frequency and output voltage ripple adjustment. The hysteresis window setup is decided by a two-resistor voltage divider on VREFB and VHYST pin. Two times the voltage drop on the top resistor is the hysteresis window. The formula is shown in the following:

$$V_{hyswindow} = 2 \times VREFB \times (1 - \frac{R13}{R11 + R13})$$

Where V<sub>hyswindow</sub> is the hysteresis window (V); VREFB is the regulated voltage from VREVB (pin 5); R11 is the top resistor in the voltage divider; R13 is the bottom resistor in the voltage divider. The maximum hysteresis window is 60 mV.

#### slow-start

Slow-start reduces the start-up stresses on the power-stage components and reduces the input current surge. The minimum slow-start time is limited to 1 ms due to the power good function deglitch time. Slow-start timing is dependent on the timing capacitor value on the slow-start pin and the total resistance on VREFB. The following formula can be used for setting the slow-start timing:

$$T_{SLOW-START} = 5 \times C_{SLOW-START} \times R_{VREFB}$$

 $T_{SLOW-START}$  is the slow-start time;  $C_{SLOW-START}$  is the capacitor value on SLOWST (pin 3).  $R_{VREFB}$  is the total resistance on VREFB (pin 5).

#### current limit

Current limit is implemented using the on-resistance of the upper FETs as the sensing elements. The IOUT signal is used for the current limit and the droop function. The voltage at IOUT at the output current trip point will be:

$$V_{IOUT} = R_{ON} \times I_{O} \times 2$$

 $R_{ON}$  is the high-side on-time resistance;  $I_{O}$  is the output current. The current limit is calculated by using the equation:

$$R5 = \frac{R4 \times \left(I_{O(MAX)} \times 2 \times R_{ON} - 0.125\right)}{0.125}$$

Where R4 is the bottom resistor in the voltage divider on OCP pin, and R5 is the top resistor;  $I_{O(MAX)}$  is the maximum current allowed;  $R_{ON}$  is the high-side FET on-time resistance.

Since the FET on-time resistance varies according to temperature, the current limit is basically for catastrophic failure.



#### APPLICATION INFORMATION

#### droop compensation

Droop compensation with the offset resistor divider from  $V_{OUT}$  to the VSENSE is used to keep the output voltage in range during load transients by increasing the output voltage setpoint toward the upper tolerance limit during light loads and decreasing the voltage setpoint toward the lower tolerance limit during heavy loads. This allows the output voltage to swing a greater amount and still remain within the tolerance window. The maximum droop voltage is set with R6 and R7:

$$V_{DROOP(max)} = V_{IOUT(max)} \times \frac{R6}{R6 + R7}$$

Where  $V_{DROOP(max)}$  is the maximum droop voltage;  $V_{IOUT(max)}$  is the maximum  $V_{IOUT}$  that reflects the maximum output current (full load); R6 is the bottom resistor of the divider connected to the DROOP pin, R7 is the top resistor.

The offset voltage is set to be half of the maximum droop voltage higher than the nominal output voltage, so the whole droop voltage range is symmetrical to the nominal output voltage. The formula for setting the offset voltage is:

$$V_{OFFSET} = \frac{1}{2} \times V_{DROOP(max)} = V_{O} \times \left(\frac{R12}{R10 + R12}\right)$$

Where  $V_{OFFSET}$  is the desired offset voltage;  $V_{DROOP(max)}$  is the droop voltage at full load;  $V_O$  is the nominal output voltage; R10 is the top resistor of the offset resistor divider, and R12 is the bottom one.

Therefore, with the setup above, at light load, the output voltage is:

$$V_{O(NO\ LOAD)} = V_{O(nom)} + V_{OFFSET} = V_{O(nom)} + \frac{1}{2} \times V_{DROOP}$$

And, at full load, the output voltage is:

$$V_{O(FULL\ LOAD)} = V_{O(nom)} - V_{OFFSET} = V_{O(nom)} - \frac{1}{2} \times V_{DROOP}$$

#### output inductor ripple current

The output inductor current ripple can affect not only the efficiency, but also the output voltage ripple. The equation for calculating the inductor current ripple is exhibited in the following:

$$I_{ripple} = \frac{V_{IN} - V_{OUT} - I_{OUT} \times (r_{DS(on)} + R_L)}{L_{OUT}} \times D \times Ts$$

Where  $I_{ripple}$  is the peak-to-peak ripple current (A) through the inductor;  $V_{IN}$  is the input voltage (V);  $V_{OUT}$  is the output voltage (V);  $I_{OUT}$  is the output current;  $I_{DS(on)}$  is the on-time resistance of MOSFET ( $\Omega$ );  $I_{OUT}$  is the output inductor equivalent series resistance; D is the duty cycle; and Ts is the switch cycle (S). From the equation, it can be seen that the current ripple can be adjusted by changing the output inductor value.

Example:

$$V_{IN}=5~V;~V_{OUT}=1.8~V;~I_{OUT}=5~A;~r_{DS(on)}=10~m\Omega;~R_L=5~m\Omega;~D=0.36;~Ts=5~\mu s;~L_{OUT}=6~\mu H$$
 Then, the ripple  $I_{ripple}=1~A.$ 



#### APPLICATION INFORMATION

#### output capacitor RMS current

Assuming the inductor ripple current totally goes through the output capacitor to ground, the RMS current in the output capacitor can be calculated as:

$$I_{O(rms)} = \frac{\Delta I}{\sqrt{12}}$$

Where  $I_{O(rms)}$  is the maximum RMS current in the output capacitor (A);  $\Delta I$  is the peak-to-peak inductor ripple current (A).

Example:

$$\Delta I = 1 \text{ A, so } I_{O(rms)} = 0.29 \text{ A}$$

#### input capacitor RMS current

The input capacitor RMS current is important for input capacitor design. Assuming the input ripple current totally goes into the input capacitor to the power ground, the RMS current in the input capacitor can be calculated as:

$$I_{I(rms)} = \sqrt{I_O^2 \times D \times (1 - D) + \frac{1}{12} \times D \times I_{ripple}^2}$$

Where  $I_{l(rms)}$  is the input RMS current in the input capacitor (A);  $I_{O}$  is the output current (A);  $I_{ripple}$  is the peak-to-peak output inductor ripple current; D is the duty cycle. From the equation, it can be seen that the highest input RMS current usually occurs at the lowest input voltage, so it is the worst case design for input capacitor ripple current.

Example:

$$I_O = 5 \text{ A}$$
; D = 0.36;  $I_{ripple} = 1 \text{ A}$ , Then,  $I_{I(rms)} = 2.46 \text{ A}$ 

#### layout and component value consideration

Good power supply results will only occur when care is given to proper design and layout. Layout and component value will affect noise pickup and generation and can cause a good design to perform with less than expected results. With a range of current from milliamps to tens or even hundreds of amps, good power supply layout and component selection, especially for a fast ripple controller, is much more difficult than most general PCB design. The general design should proceed from the switching node to the output, then back to the driver section, and, finally, to placing the low-level components. In the following list are several specific points to consider before layout and component selection for TPS56302:

- All sensitive analog components should be referenced to ANAGND. These include components connected to SLOWST, DROOP, IOUT, OCP, VSENSE, VREFB, VHYST, BIAS, and LOSENSE/LOHIB.
- 2. The input voltage range for TPS56302 is low from 2.8-V to 5.5-V, so it has a voltage tripler (charge pump) inside to deliver proper voltage for internal circuitry. To avoid any possible noise coupling, a low ESR capacitor on V<sub>CC</sub> is recommended.
- 3. For the same reason in Item 2, the ANAGND and DRVGND should be connected as close as possible to the IC.
- 4. The bypass capacitor should be placed close to the TPS56302.

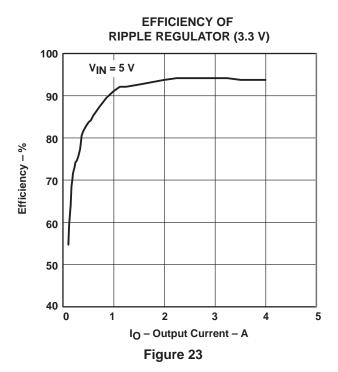


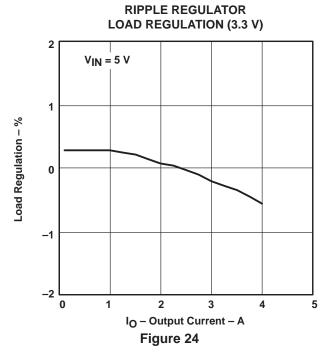
#### **APPLICATION INFORMATION**

#### layout and component value consideration (continued)

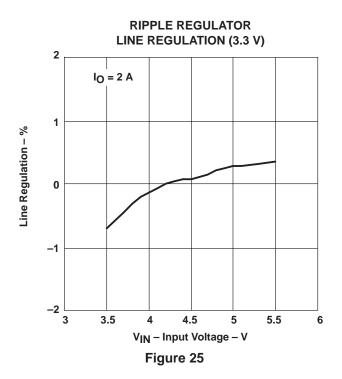
- 5. When configuring the high-side driver as a boot-strap driver, the connection from BOOTLO to the power FETs should be as short and as wide as possible. LOSENSE/LOHIB should have a separate connection to the FETs since BOOTLO will have large peak current flowing through it.
- The bulk storage capacitors across V<sub>IN</sub> should be placed close to the power FETs. High-frequency bypass
  capacitors should be placed in parallel with the bulk capacitors and connected close to the drain of the
  high-side FET and to the source of the low-side FET.
- 7. HISENSE and LOSENSE/LOHIB should be connected very close to the drain and source, respectively, of the high-side FET. HISENSE and LOSENSE/LOHIB should be routed very close to each other to minimize differential-mode noise coupling to these traces. Ceramic decoupling capacitors should be placed close to where HISENSE connects to V<sub>IN</sub>, to reduce high-frequency noise coupling on HISENSE.

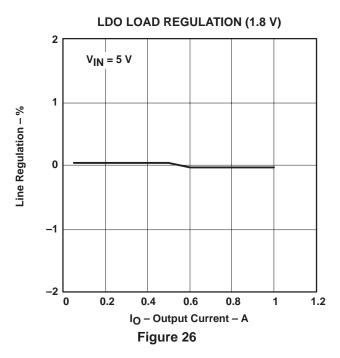
The EVM board (SLVP-139) is used in the test. The test results are shown in the following.

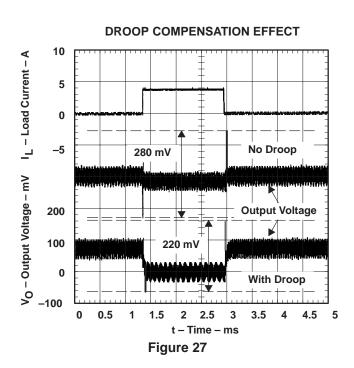


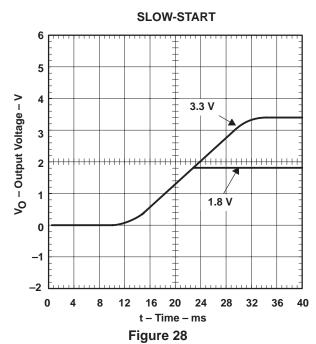


#### **APPLICATION INFORMATION**









#### **APPLICATION INFORMATION**

#### layouts

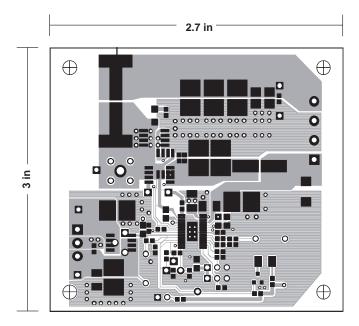


Figure 29. Top Layer

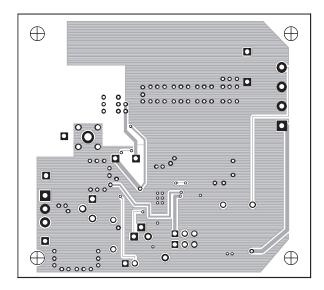


Figure 30. Bottom Layer (Top View)

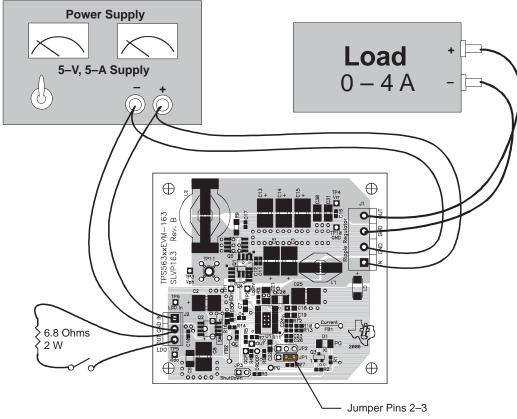
#### **APPLICATION INFORMATION**

#### bill of materials

| REF                              | PN           | Description                                        | MFG          | Size                 |
|----------------------------------|--------------|----------------------------------------------------|--------------|----------------------|
| C1                               | 10TPA33M     | Capacitor, POSCAP, 33 μF, 10 V                     | Sanyo        | С                    |
| C2, C20, C21, C30, C31           | Std          | Capacitor, Ceramic, 10 μF, 16 V                    | Sanyo        | 1210                 |
| C3. C6, C8, C13, C25             | 6TPB150M     | Capacitor, POSCAP, 150 μF, 6 V                     | Sanyo        | D                    |
| C4, C5, C11, C12, C23, C26, C27, | Std          | Capacitor, Ceramic, 0.1 μF, 16 V                   | Sanyo        | 603                  |
| C7, C22                          | Std          | Capacitor, Ceramic, 1 μF, 16 V                     | Sanyo        | 805                  |
| C9                               | Std          | Open                                               |              | 1210                 |
| C10, C16                         | Std          | Open                                               |              | 603                  |
| C14, C15                         | Std          | Open                                               |              | D                    |
| C17, C24                         | Std          | Capacitor, Ceramic, 1000 pF, 16 V                  | Sanyo        | 603                  |
| C18, C19                         | Std          | Capacitor, Ceramic, 1 μF, 16 V                     | Sanyo        | 805                  |
| D1                               | SML-LX2832G  | Diode, LED, Green, 2.1 V SM                        | Lumwx        | 1210                 |
| L1, L2                           | DO3316P-332  | Inductor, 3.3 μH, 5.4 A                            | Coilcraft    | $0.5 \times 0.37$ in |
| J1                               | ED2227       | Terminal Block, 4-pin, 15 A, 5.08 mm               | OST          | 5.08 mm              |
| J2                               | ED1515       | Terminal Block, 3-pin, 6 A, 3.5 mm                 | OST          | n, 6 A,              |
| JP1, JP2                         | S1132-3-ND   | Header, Right straight, 3-pin, 0.1 ctrs, 0.3" pins | Sullins      | #S1132-3-ND          |
| JP1shunt                         | 929950-00-ND | Shunt jumper, 0.1" (for JP1)                       | 3M           | 0.1"                 |
| J3                               | S1132-2-ND   | Header, Right straight, 2-pin, 0.1 ctrs, 0.3" pins | Sullins      | #S1132-2-ND          |
| Q1                               |              | Open                                               |              | SO-8                 |
| Q2:A, Q4, Q5                     | IRF7811      | MOSFET, N-ch, 30 V, 10 mΩ                          |              | SO-8                 |
| Q2:B                             |              | Open                                               |              | TO-220               |
| Q3                               | 2N7002DICT-N | MOSFET, N-ch, 115 mA, 1.2 Ω                        | Diodes, Inc. | TO-236               |
| R3                               | std          | Resistor, 10 kohms, 5 %                            |              | 603                  |
| R4                               | std          | Resistor, 1 kohms, 1%                              |              | 603                  |
| R5                               | std          | Resistor, 0 ohms, 1%                               |              | 603                  |
| R6                               | std          | Resistor, 1 kohms, 1%                              |              | 603                  |
| R7                               | std          | Resistor, 3.32 kohms, 1%                           |              | 603                  |
| R8                               | std          | Resistor, 10 ohms, 5 %                             |              | 603                  |
| R9                               | std          | Resistor, 2.7 ohms, 5 %                            |              | 1206                 |
| R10                              | std          | Resistor, 150 ohms, 5 %                            |              | 603                  |
| R11                              | std          | Resistor, 100 ohms, 1 %                            |              | 603                  |
| R12                              | std          | Resistor, 10 kohms, 5 %                            |              | 603                  |
| R13                              | std          | Resistor, 20.0 kohms, 1 %                          |              | 603                  |
| R14                              | std          | Resistor, 0 ohms, 5%                               |              | 603                  |
| R15                              | std          | Resistor, open                                     |              | 603                  |
| R16                              | std          | Resistor, 15 kohms, 5 %                            |              | 805                  |
| TP1-TP10                         | 240–345      | Test Point, Red                                    | Farnell      |                      |
| TP11                             | 131–4244–00  | Adaptor, 3.5-mm probe clip (or 131–5031–00)        | Tektronix    |                      |
| U1                               | TPS56302PWP  | Dual controller                                    |              | TSSOP-28pin          |



#### **APPLICATION INFORMATION**



NOTE A: All wire pairs should be twisted.

Figure 31. Test Setup



#### **APPLICATION INFORMATION**

#### **DSP** power application

In DSP power applications, TPS56302 is used in the applications that require more current for peripheral and DSP I/O. The power good (PG) output can be used for monitoring or controlling as an optional function. In the EVM schematic, Q3, D1, R1, and R2 are the circuit to show this function.

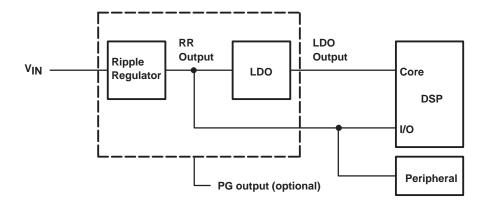


Figure 32. TPS56302 For High Peripheral Current DSP Application

TPS56300 is used in the applications that require high current for core, but low current for I/O. Another important feature is that, if the input voltage is the same as the LDO output, the LDO switch acts as a distribution switch to control the on/off of the LDO output.

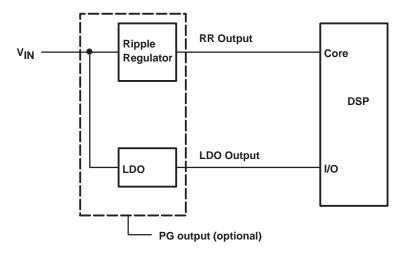


Figure 33. TPS56300 For On/Off Control DSP Application

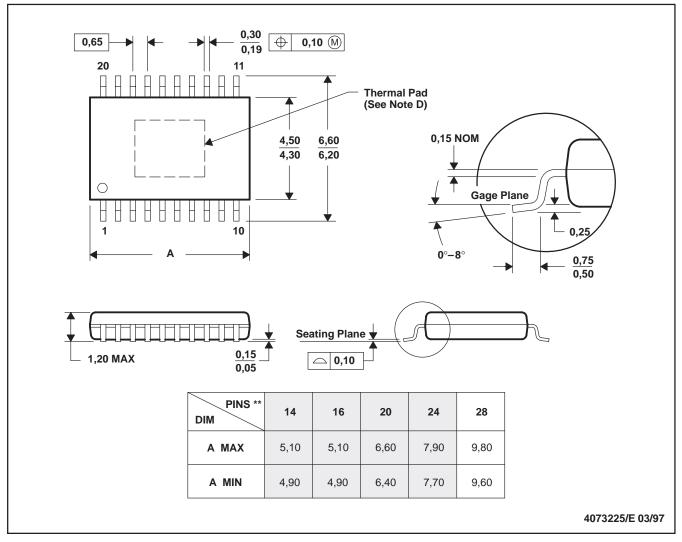


#### **MECHANICAL DATA**

#### PWP (R-PDSO-G\*\*)

#### PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

#### **20-PIN SHOWN**



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusions.
  - D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected leads.
  - E. Falls within JEDEC MO-153

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